

IN THE SPECIFICATION

At page 1, line 2, please add the following:

--Cross-Reference To Related Applications

Q1  
This application is a continuation of U.S. Application Serial No. 09/212,150, filed December 15, 1998, entitled A Nitride Semiconductor Light Emitting Device Having A Silver P-Contact, incorporated herein by reference.--

Q2  
Page 5, line 18, after "(annealing 1).", insert --Other metals that can be used to form metal layer 21A are aluminum and indium.--

Q3  
Page 6, line 21, after "dielectric.", insert --Examples of suitable metals include nickel, palladium, and platinum.--

REMARKS

New Claims 1-36 are pending. The independent Claim 1 is patentable for at least the reasons that the claims in the parent application were deemed patentable by the Examiner.

Independent Claims 18 and 36 are patentable for at least the reasons that Claim 1 is patentable.

Support for the insert on page 5, line 18, is found in Claims 6 and 9 in the original parent application. Support for the insert on page 6, line 21, is found in Claim 4 of the original parent application.

EXPRESS MAIL LABEL NO:

EL699361114US

Respectfully submitted,

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